

# DONGGUAN NANJING ELECTRONICS LTD., Transient Voltage Suppressor

**Micro-Packaged Diode for ESD Protection** 

## **ESD5VC**

The ESD5VC Series is designed to protect voltage sensitive components from damage or latch-up due to ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD for board level. Because of its small size and bi-directional design, it is ideal for use in cellular phones, MP3 players, and portable applications that require audio line protection.

#### **Specification Features**

- Small Body Outline Dimensions:
  - nom 0.039" x 0.024" (1.0x0.6 mm)
- Low Body Height: nom 0.019" (0.5 mm)
- Low Capacitance 12 pF
- Low Clamping Voltage
- Reverse Working (Stand-off) Voltage: 5.0 V
- Low Leakage
- Response Time is Typically < 1 ns</li>
- IEC61000-4-2 Level 4 ESD Protection
- This is a Pb-Free Device

#### Mechanical Characteristics:

- CASE: Void-free, transfer-molded, thermosetting plastic Epoxy Meets UL 94 V-0
- LEAD FINISH: NiPdAu
- MOUNTING POSITION: Any
- QUALIFIED MAX REFLOW TEMPERATURE: 260°C
- Device Meets MSL 1 Requirements
- RoHS/WEEE Compliant
- Marking: Marking code

#### **Applications**

- Cellular Handsets & Accessories
- Personal Digital Assistants (PDAs)
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- MP3 Players

#### **Maximum Ratings**

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Contact		±30	kV
Peak Power Per 8 x 20µs Waveform	P <sub>PK</sub>	100	W
Total Power Dissipation on FR-5 <sup>®</sup> Board @ TA = 25°C	P <sub>D</sub>	300	mW
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
Lead Solder Temperature - Maximum (10 Second Duration)	TL	260	°C

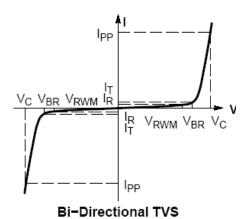
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Note1: FR-5 =1.0\*0.75\*0.062inch (25.4\*19.05\*1.58mm).

#### **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted.})$ 

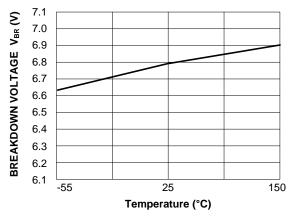
Symbol	Parameter		
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current		
V <sub>C</sub>	Clamping Voltage @ IPP		
$V_{RWM}$	Working Peak Reverse Voltage		
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>		
I <sub>T</sub>	Test Current		
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>		
$P_{PK}$	Peak Power Dissipation		
С	Max. Capacitance @ $V_R = 0$ and freq.=1 MHz		



Device Mark		V <sub>RWM</sub>	I <sub>R</sub> ( μA) @ V <sub>RWM</sub>		V <sub>BR</sub> (V) @ I <sub>T</sub>			I <sub>T</sub>	Max. V <sub>C</sub> (V)	С
	(/	(V)	Тур.	Max.	Min.	Тур.	Max.	(mA)	@ I <sub>PP</sub> <sup>©</sup> =1A	(pF)
TSD05DF	С	5.0	0.05	1	6.5	6.8/7.6	8	1	9.8	12

Note2: Surge current wave form per figure 3.

#### TYPICAL CHARACTERISTICS



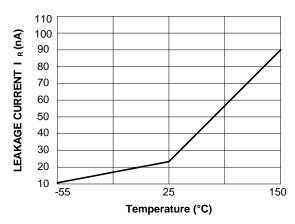


Figure 1: Typical Breakdown Voltage versus Temperature

Figure 2: Typical Leakage Current versus Temperature

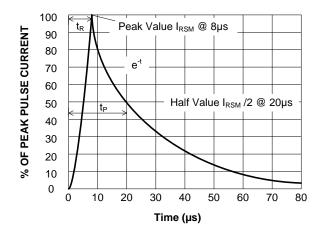
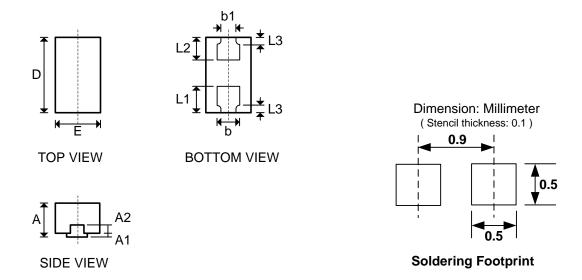


Figure 3: 8/20µs Pulse Wave Form

## PACKAGE OUTLINE DIMENSIONS

## DFN1006-2L



Symbol	Dimensions in mm					
Symbol	MIN.	NOM.	MAX.			
Α	0.450	0.500	0.550			
A1	0.000	-	0.050			
A2	0.150REF.					
D	0.950	1.000	1.050			
E	0.550	0.600	0.650			
b	0.250	0.300	0.350			
b1	0.150	0.200	0.250			
L1	0.300	0.350	0.400			
L2	0.250	0.300	0.350			
L3	0.100REF.					